



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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TECHNOLOGY CENTER 2800
Group Art Unit: 2800

In re the Application of: **OHSAKA, et al.**

Serial No.: **09/456,531**

Examiner: **James A. Menefee**

Filed: **December 8, 1999**

FOR: **ELECTRODE STRUCTURE, PROCESS FOR FABRICATING ELECTRODE
STRUCTURE AND SEMICONDUCTOR LIGHT-EMITTING DEVICE**

AMENDMENT ACCOMPANYING REQUEST FOR CONTINUED EXAMINATION

Commissioner for Patents
Washington, D.C. 20231

July 24, 2002

Sir:

In response to the Office Action dated **March 25, 2002**, extended to **July 25, 2002** by a one month Petition for Extension of Time, please amend the above-identified application as follows:

CLEAN VERSION OF AMENDMENTS

IN THE CLAIMS:

Please amend claims 1-3, 5, 7-8 and 13-14 as follows:

1. (Amended) An electrode structure including a conductive film formed on an insulation film without penetrating the insulation film, the insulation film being formed on a base substrate.

the insulation film comprising a plurality of poles of polyimide, a first film formed on side surfaces of the poles and formed of an insulation material having a higher hardness than polyimide, and a second film of polyimide buried among said a plurality of poles with the first film formed on the side surfaces thereof.